

MITSUBISHI SEMICONDUCTOR <GaAs FET>
MGFS48V2527
2.5 - 2.7GHz BAND 60W GaAs FET

DESCRIPTION

The MGFS48V2527 is a 60W push-pull type GaAs Power FET especially designed for use in 2.5 - 2.7GHz band amplifiers. The hermetically sealed metal-ceramic package guarantees high reliability.

FEATURES

- Push-pull configuration
- High output power
Pout = 60W (TYP.) @ f=2.5 - 2.7 GHz
- High power gain
GLP = 10 dB (TYP.) @ f=2.5 - 2.7GHz
- High power added efficiency
P.A.E. = 45 % (TYP.) @ f=2.5 - 2.7GHz

APPLICATION

2.5-2.7GHz band power amplifier

QUALITY GRADE

IG

RECOMMENDED BIAS CONDITIONS

- VDS = 12 (V)
- ID = 4.0 (A)
- RG=20 (ohm) for each gate

ABSOLUTE MAXIMUM RATINGS (Ta=25deg.C)

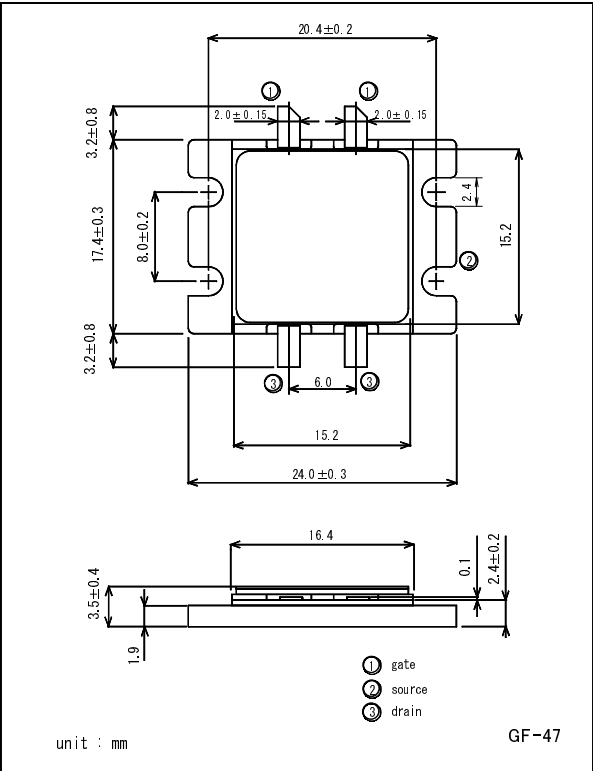
Symbol	Parameter	Ratings	Unit
VGDO	Gate to drain voltage	-20	V
VGSO	Gate to source voltage	-10	V
PT *1	Total power dissipation	107.1	W
Tch	Channel temperature	175	deg.C
Tstg	Storage temperature	-65 / +175	deg.C

*1 : Tc=25deg.C

ELECTRICAL CHARACTERISTICS (Ta=25deg.C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
VGS(off)	Cut-off voltage	VDS = 3V , ID = 17.3mA	-1	-	-4	V
P2dB	Output power at 2dB gain compression	VDS=12V, ID(RF off)=4.0A, f=2.5 - 2.7GHz	47	48	-	dBm
GLP	Linear power gain		9	10	-	dB
ID(RF)	Drain current		-	11	15	A
P.A.E.	Power added efficiency		-	45	-	%
Rth (Ch-C)	Thermal resistance	Channel to Case	-	1.0	1.4	deg.C/W

OUTLINE



< Keep safety first in your circuit designs! >
Mitsubishi Electric Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary circuits, (2) use of non-flammable material or (3) prevention against any malfunction or mishap.

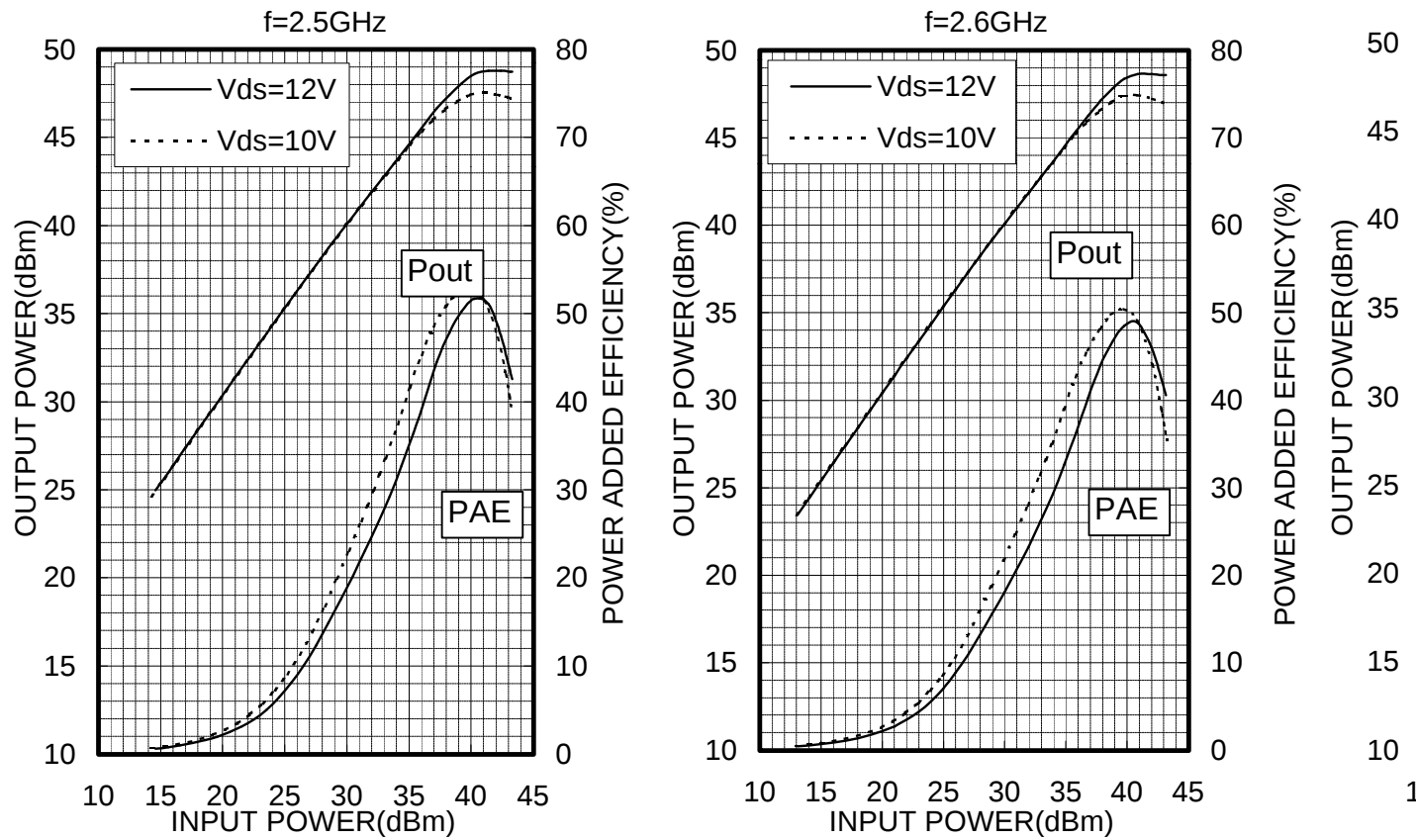


MITSUBISHI
ELECTRIC

June-'04

MGFS48V2527

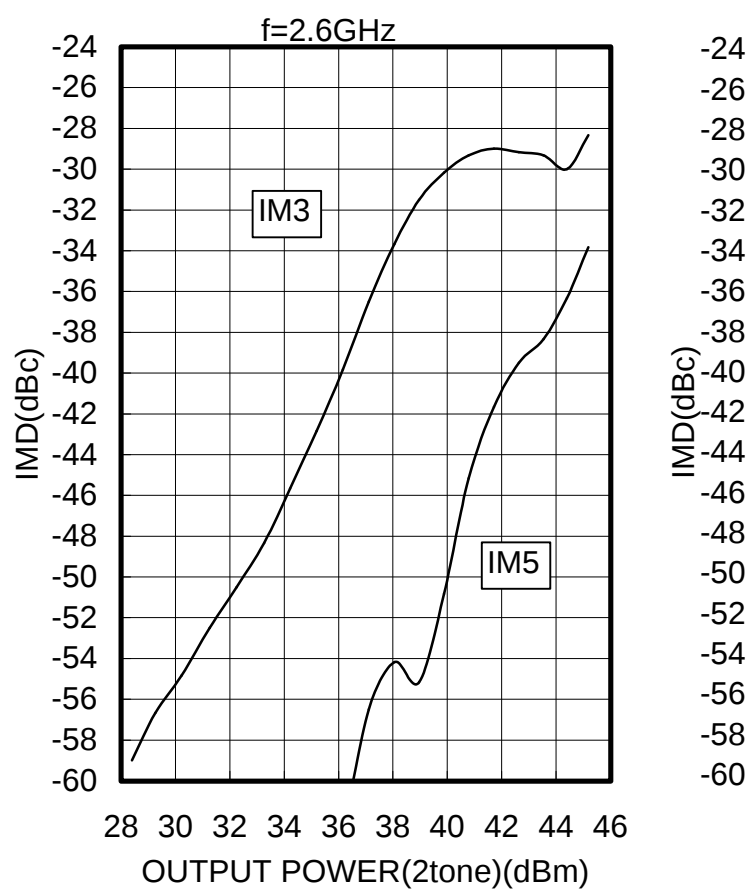
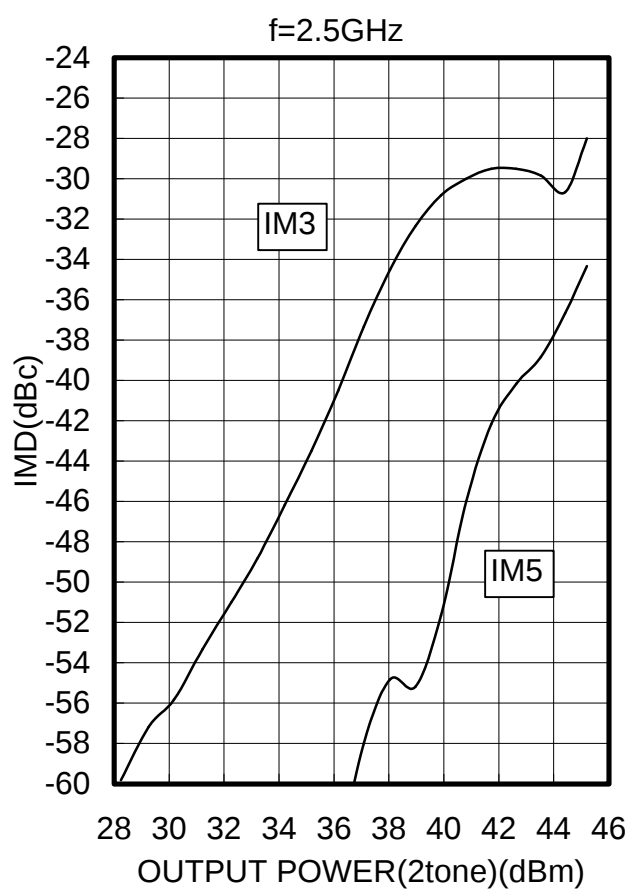
OUTPUT POWER & POWER ADDED EFFICIENCY vs. INPUT POWER
TEST CONDITIONS : $I_{ds}(RFoff)=4A$



MGFS48V2527

IMD vs. OUTPUT POWER

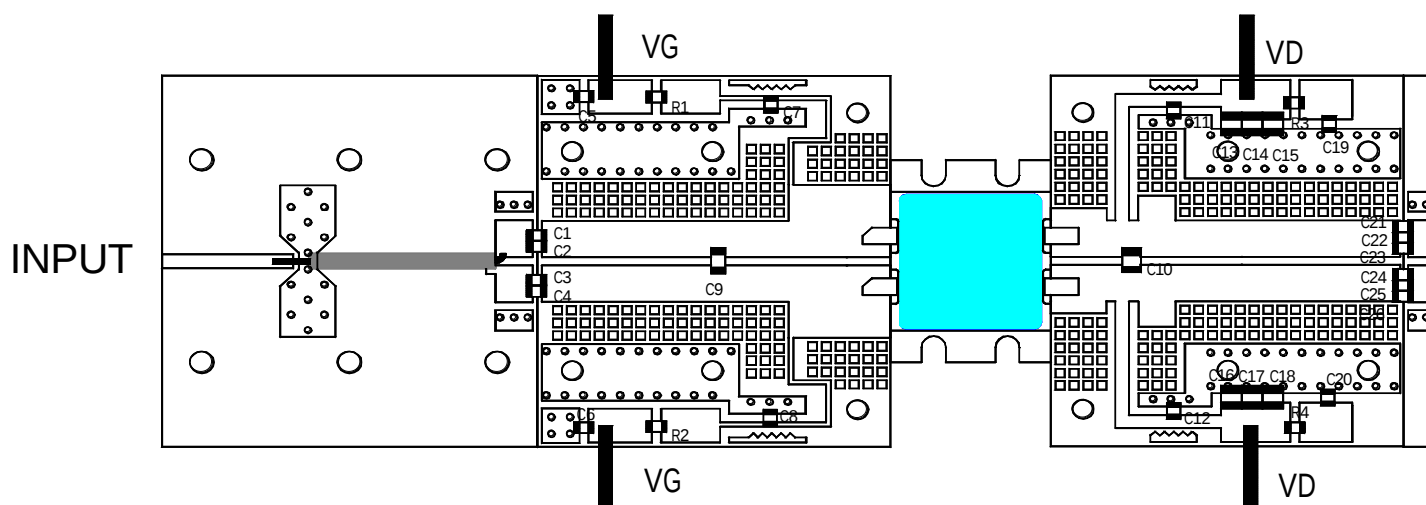
TEST CONDITIONS : $V_{DS}=12V, I_{D(RF\ off)}=4.0A$
2-tone test , $\Delta f=5MHz$



MGFS48V2527

TEST CIRCUIT

MGFS48V2527



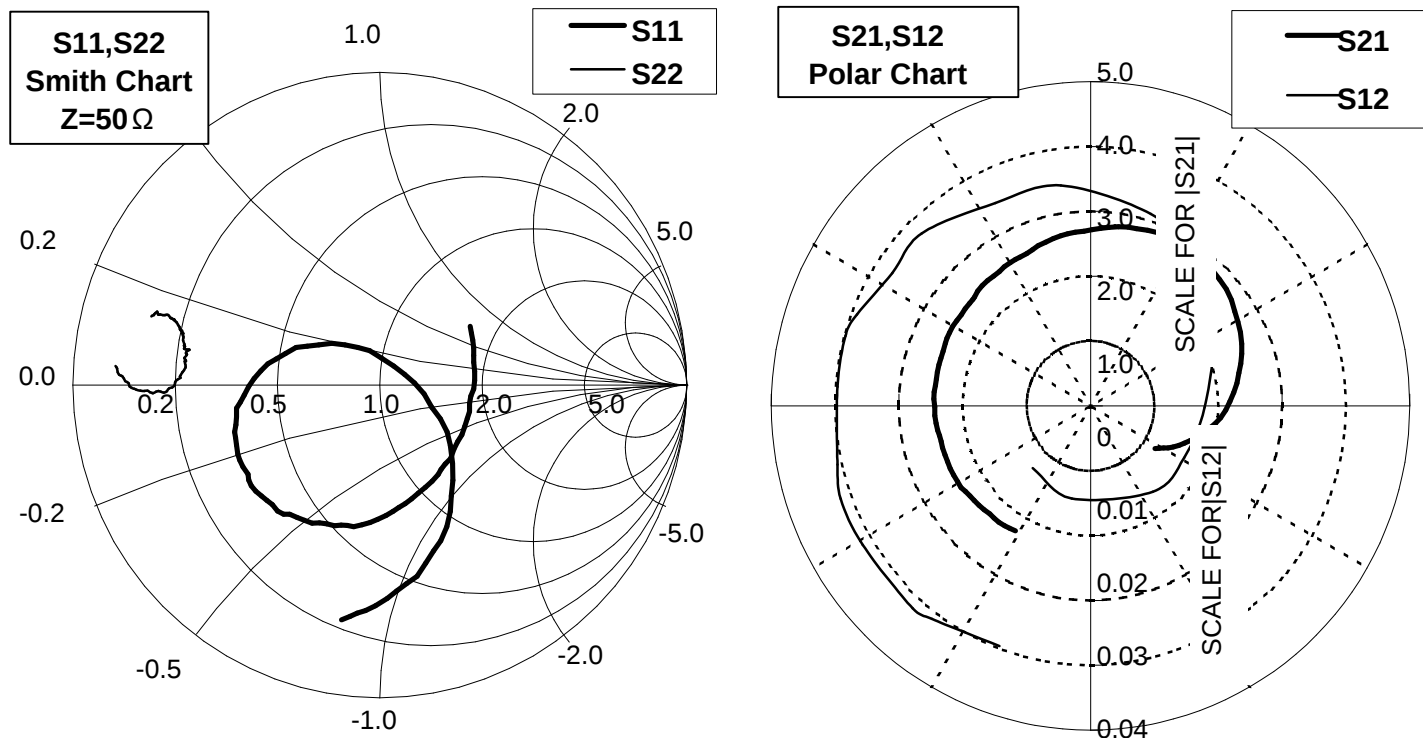
C1, C2, C3, C4	: 8pF (GR708)
C5, C6	: 1000pF (GR40)
C7, C8	: 20pF (GR40)
C9	: 1.5pF (GR111)
C10	: 1pF (GR111)
C11, C12	: 20pF (GR40)
C13, C14, C15	: 4.7 μ F (CM32B475K)
C16, C17, C18	: 4.7 μ F (CM32B475K)
C19, C20	: 1000pF (GR40)
C21, C22, C23, C24, C25, C26	: 13pF (GR708)
R1, R2	: 20ohm
R3, R4	: 51ohm

Board material
Specific dielectric

MITSUBISHI ELECTRIC CORPORATION

MGFS48V2527

TEST CONDITIONS : $f=2.0\text{-}3.0\text{GHz}$, $V_{DS}=12\text{V}$, $I_D=2.0\text{A}$



S PARAMETERS (Ta=25deg.C, VDS=12V, ID=2.0A)

f (GHz)	S Parameters (TYP.)							
	S11		S21		S12		S22	
	Mag.	Ang(deg.)	Mag.	Ang(deg.)	Mag.	Ang(deg.)	Mag.	Ang(deg.)
2.00	0.343	30.9	2.394	-124.1	0.042	-112.1	0.773	164.4
2.05	0.311	11.3	2.448	-135.3	0.042	-129.0	0.760	163.0
2.10	0.301	-13.6	2.529	-147.0	0.046	-134.8	0.746	163.3
2.15	0.318	-37.2	2.575	-159.1	0.042	-148.3	0.724	162.9
2.20	0.354	-57.5	2.594	-170.4	0.044	-160.2	0.700	163.5
2.25	0.399	-78.1	2.620	176.5	0.045	-167.5	0.690	164.1
2.30	0.452	-94.0	2.597	164.9	0.039	176.5	0.673	165.6
2.35	0.484	-107.7	2.603	153.3	0.042	164.3	0.659	166.6
2.40	0.512	-121.8	2.558	141.8	0.040	161.2	0.655	167.8
2.45	0.529	-134.1	2.569	130.9	0.037	147.6	0.649	169.7
2.50	0.523	-145.4	2.573	119.6	0.039	135.6	0.629	170.7
2.55	0.504	-159.0	2.629	106.5	0.032	121.1	0.636	172.5
2.60	0.460	-171.7	2.665	92.9	0.034	100.6	0.636	175.1
2.65	0.369	171.2	2.734	78.3	0.030	78.4	0.645	177.6
2.70	0.231	149.6	2.731	59.9	0.027	58.1	0.666	-179.9
2.75	0.074	85.3	2.623	41.6	0.022	31.9	0.695	-177.4
2.80	0.188	-26.1	2.380	22.2	0.014	-3.2	0.740	-177.1
2.85	0.395	-53.1	2.085	4.0	0.014	-39.0	0.781	-177.8
2.90	0.569	-72.1	1.730	-13.8	0.018	-60.5	0.818	-179.5
2.95	0.694	-88.0	1.389	-28.6	0.016	-111.6	0.844	178.8
3.00	0.773	-99.3	1.108	-40.4	0.015	-136.5	0.862	176.7

This S-Parameter data show measurements performed on each single-ended FET.

MITSUBISHI ELECTRIC CORPORATION

June-'04

MGFS48V2527**2.5 - 2.7GHz BAND 60W GaAs FET****Requests Regarding Safety Designs**

Mitsubishi Electric constantly strives to raise the level of its quality and reliability. Despite these concerted efforts, however, there will be occasions when our semiconductor products suffer breakdowns, malfunctions or other problems. In view of this reality, it is requested that every feasible precaution be taken in the pursuit of redundancy design, malfunction prevention design and other safety-related designs, to prevent breakdowns or malfunctions in our products from resulting in accidents involving people, fires, social losses or other problems, thereby upholding the highest levels of safety in the products when in use by customers.

Matters of Importance when Using these Materials

1. These materials are designed as reference materials to ensure that all customers purchase Mitsubishi Electric semiconductors best suited to their specific use applications. Please be aware, however, that the technical information contained in these materials does not comprise consent for the execution or use of intellectual property rights or other rights owned by Mitsubishi Electric Corporation.
2. Mitsubishi Electric does not assume responsibility for damages resulting from the use of product data, graphs, charts, programs, algorithms or other applied circuit examples described in these materials, or for the infringement of the rights of third-party owners resulting from such use.
3. The data, graphs, charts, programs, algorithms and all other information described in these materials were current at the issue of these materials, with Mitsubishi Electric reserving the right to make any necessary updates or changes in the products or specifications in these materials without prior notice. Before purchasing Mitsubishi Electric semiconductor products, therefore, please obtain the latest available information from Mitsubishi Electric directly or an authorized dealer.
4. Every possible effort has been made to ensure that the information described in these materials is fully accurate. However, Mitsubishi Electric assumes no responsibility for damages resulting from inaccuracies occurring within these materials.
5. When using the product data, technical contents indicated on the graphs, charts, programs or algorithms described in these materials, assessments should not be limited to only the technical contents, programs and algorithm units. Rather, it is requested that ample evaluations be made of each individual system as a whole, with the customer assuming full responsibility for decisions on the propriety of application. Mitsubishi Electric does not accept responsibility for the propriety of application.
6. The products described in these materials, with the exception of special mention concerning use and reliability, have been designed and manufactured with the purpose of use in general electronic machinery. Accordingly these products have not been designed and manufactured with the purpose of application in machinery or systems that will be used under conditions that can affect human life, or in machinery or systems used in social infrastructure that demand a particularly high degree of reliability. When considering the use of the products described in these materials in transportation machinery (automobiles, trains, vessels), for objectives related to medical treatment, aerospace, nuclear power control, submarine repeaters or systems or other specialized applications, please consult with Mitsubishi Electric directly or an authorized dealer.
7. When considering use of products for purposes other than the specific applications described in these materials, please inquire at Mitsubishi Electric or an authorized dealer.
8. The prior consent of Mitsubishi Electric in writing is required for any reprinting or reproduction of these materials.
9. Please direct any inquiries regarding further details of these materials, or any other comments or matters of attention, to Mitsubishi Electric or an authorized dealer.

